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## ISL8205MEVAL1Z

Evaluation Board User Guide

# USER'S MANUAL

UG072 Rev 0.00 May 3, 2016

The **ISL8205M** power module is a single channel synchronous step-down complete power supply, capable of delivering up to 5A of continuous current. Operating from a single 2.6V to 5.5V input power rail and integrating a controller, power inductor and MOSFETs, ISL8205M can achieve up to 95% conversion efficiency. It also provides fast transient response with excellent loop stability as well as deliver output voltage as low as 0.6V. Switching frequency is also adjustable from 680kHz to 3.5MHz with either external resistor or SYNC clock option. Selectable PFM mode can also be enabled to boost up light load efficiency to extend battery life. Other features include programmable soft-start, soft-stop, input undervoltage lockout, 100% duty cycle operation, over-temperature, overcurrent/short-circuit with hiccup mode, overvoltage and negative overcurrent protection. It also has a dedicated enable pin and power-good flag that allow for easy system power rails sequencing.

The ISL8205MEVAL1Z evaluation board is designed to demonstrate the performance of the ISL8205M. The board is by default set to be 1.2V output voltage with 1.6MHz switching frequency. Other output voltage values can be easily set by changing the jumper position. Switching frequency can be adjusted by changing the FS pin resistor.

## References

ISL8205M datasheet

### **Features**

- 2.6V to 5.5V input voltage range
- Adjustable output voltage as low as 0.6V with ±1.6% accuracy over line/load/temperature
- Default 1.8MHz current mode control operations
  - 680kHz to 3.5MHz resistor adjustable
  - External synchronization up to 3.5MHz
  - Selectable light-load efficiency mode
  - 100% duty cycle LDO mode
- · Programmable soft-start and soft-stop output discharge
- Dedicated enable pin and power-good flag
- UVLO, over-temperature, overcurrent, overvoltage and negative overcurrent protections

### Specifications/Default Set-Up

- V<sub>IN</sub> = 2.6V to 5.5V
- V<sub>OUT</sub> options (via jumper selection): 1V, 1.2V, 2.5V, 3.3V
- MAX I<sub>OUT</sub> up to 5A
- f<sub>SW</sub> = 1.6MHz by default
- · Set to PWM mode by default
- 1ms soft-start time by default

### **Ordering Information**

PART NUMBER	DESCRIPTION
ISL8205MEVAL1Z	ISL8205M single 5A power module evaluation board



FIGURE 1. ISL8205MEVAL1Z BLOCK DIAGRAM



	TABLE 1. ISL8205M COMPONENT SELECTION GUIDE MATRIX									
V <sub>IN</sub> (V)	V <sub>OUT</sub> (V)	f <sub>SW</sub> (MHz)	C <sub>IN</sub> (μF)	C <sub>OUT</sub> (μF)	R <sub>7</sub> (kΩ)	R <sub>SET</sub> (kΩ)	C <sub>FF</sub> (pF)			
5	0.6	0.8	2x22	1x100	261	OPEN	390			
5	0.9	1.2	2x22	3x22	169	200	560			
5	1	1.3	2x22	3x22	154	150	560			
5	1	1.3	2x22	2x22	154	150	820			
5	1.2	1.6	2x22	2x22	124	100	820			
5	1.5	1.7	2x22	2x22	115	66.5	560			
5	1.8	2	2x22	2x22	95.3	49.9	470			
5	2.5	2.5	2x22	2x22	75	31.6	330			
5	3.3	3	2x22	2x22	59	22.1	330			
3.3	0.6	0.8	2x22	1x100	261	OPEN	390			
3.3	0.9	1.2	2x22	3x22	169	200	560			
3.3	1	1.3	2x22	3x22	154	150	560			
3.3	1	1.3	2x22	2x22	154	150	820			
3.3	1.2	1.6	2x22	2x22	124	100	820			
3.3	1.5	1.7	2x22	2x22	115	66.5	560			
3.3	1.8	2	2x22	2x22	95.3	49.9	470			
3.3	2.5	2.5	2x22	2x22	75	31.6	330			

TABLE 1. ISL8205M COMPONENT SELECTION GUIDE MATRIX





### **Recommended Equipment**

- OV to 5.5V power supply with at least 7A source current capability
- · Electronic load capable of sinking current up to 5A
- Digital Multimeters (DMMs)
- 100MHz quad-trace oscilloscope

# **Functional Description**

The ISL8205M is a single 5A step-down high efficiency power module optimized for FPGA, DSP and Li-ion battery power devices. The module switches at 1.8MHz by default when the FS pin is shorted to VIN. The switching frequency is also adjustable from 680kHz to 3.5MHz through a resistor from FS to SGND. To



FIGURE 3. BOTTOM OF BOARD

boost light-load efficiency, ISL8205M can also be configured to operate in PFM mode by pulling the SYNC pin to SGND. Peak current mode control scheme is implemented for fast transient response. The module utilizes internal compensation to stabilize the system and optimize transient response, which greatly simplifies the application. Other excellent features include external synchronization, 100% duty cycle operation and very low quiescent current. For further information, please refer to the ISL8205M datasheet.

### **Quick Start**

The ISL8205MEVAL1Z is set to be V<sub>OUT</sub> = 1.2V,  $f_{SW}$  = 1.6MHz by default. For other V<sub>OUT</sub> options, the recommended  $f_{SW}$  needs to be adjusted by changing resistor (R<sub>7</sub>) connected to the FS pin.



Please refer to <u>Table 1</u> for more information. The following operation procedure will be based on default setting.

- 1. Before applying power to input, ensure one shorting jumper on J1 across pins 5 and 6 is present. This selects  $V_{OUT} = 1.2V$ option.
- 2. Set the ENABLE switches SW1 to the "OFF" position.
- 3. Connect the positive of a power supply to the VIN connector and the negative of the power supply to the PGND connector. Make sure the power supply is not enabled when making connections and the input power supply voltage is set to a value between 2.6V and 5.5V.
- 4. Turn the power supply on.
- 5. Turn ENABLE switch SW1 to the "ON" position to enable module operation.
- 6. The power-good LED should illuminate in green if the module is operating properly.
- Measure output voltage, V<sub>OUT</sub>, at test points VOUT and PGND. Module output should be 1.2V.

### **Programming the Output Voltage**

The ISL8205MEVAL1Z evaluation board has several preset output voltages, 1.0V, 1.2V, 2.5V and 3.3V, which can be selected in J1 jumper. Other V<sub>OUT</sub> values other than on-board options can be set by proper selection of the resistor (R<sub>SET</sub>) connecting from FB to SGND. In this case, R<sub>SET</sub> for default options (R<sub>9</sub>, R<sub>10</sub>, R<sub>11</sub>, R<sub>12</sub>) may need to be changed. The output voltage is governed by Equation 1.

$$V_{OUT} = V_{REF} \cdot \frac{R_{SET} + 100 k\Omega}{R_{SET}}$$
(EQ. 1)

For most popular  $V_{OUT}$  values and corresponding  $R_{SET}$  values, please refer to <u>Table 1</u> for more information.

#### **Feed-Forward Capacitor Selection**

In typical applications where the output capacitors are all ceramic, a feed-forward capacitor,  $C_{FF}$  (as annotated as  $C_{12}$ ,  $C_{13}$ ,  $C_{14}$ ,  $C_{15}$  in schematic) is needed to be put in parallel with each  $R_{SET}$  to insure loop stability in extreme operating conditions. With internal compensation mode enabled, the  $C_{FF}$  values for typical operating conditions are optimized and listed in Table 1. And that's how  $C_{12}$ ,  $C_{13}$ ,  $C_{14}$ ,  $C_{15}$  default values are selected. Please note that, for system parameters that are different from Table 1 or external instead of internal compensation is used, the optimized value of  $C_{FF}$  needs to be adjusted.

### **Frequency Adjust**

The switching frequency of ISL8205M is adjustable ranging from 680kHz to 3.5MHz via a simple resistor  $R_{FS}$  (as shown in  $R_7$  on ISL8205MEVAL1Z board) across FS to SGND. The switching frequency setting is based on Equation 2:

$$R_{FS}[k\Omega] = \frac{220 \cdot 10^3}{f_{OSC}[kHz]} - 14$$
(EQ. 2)

When the FS pin is directly tied to VIN, the frequency of operation is fixed at 1.8MHz. For a recommended switching frequency with typical operation conditions, refer to Table 1. More detailed

information on recommended switching frequency and f<sub>SW</sub> selection range is provided in <u>"Recommended Switching</u> <u>Frequency"</u> and <u>"Operation Range"</u>.

#### **Recommended Switching Frequency**

Selection of switching frequency for each V<sub>IN</sub> and V<sub>OUT</sub> combination needs to take into account a few trade-offs. Generally, lower switching frequency will lead to higher efficiency. However, switching frequency should not be decreased too low due to negative current protection limit. Moreover, when output voltage is relatively high, low switching frequency will result in more sub-harmonic oscillation. Therefore, operating frequency needs to be kept relatively high under high V<sub>OUT</sub> conditions. However, again, switching frequency cannot be increased too much. Otherwise, the minimum on-time limit could be violated. Based on these considerations, Figure 4 provides the recommended switching frequency under various typical V<sub>IN</sub> and across V<sub>OUT</sub> ranges.



### **Operation Range**

By default, the ISL8205MEVAL1Z is configured to be operating at  $V_{OUT} = 1.2V$  (J1 jumper position is at pins 5 and 6),  $f_{SW} = 1.6$ MHz conditions.  $V_{IN}$  ranges from 2.6V to 5.5V. The board can also support a wider operating range to meet the requirement of specific applications. The  $V_{OUT}$  can be adjusted from 0.6V to 5V. Load current range is from 0A to 5A. Note that, for continuous operation at 5A, airflow across the board may be needed. The  $f_{SW}$  can also be tuned. However, to ensure sufficient stability margins, switching frequency can only be adjusted within the safe operating regions represented with Figures 5 through 9. Operating outside of these areas may lead to system instability.











#### **PWM/PFM Selection**

By default, ISL8205MEVAL1Z is set to operate in PWM mode. This is achieved by connecting SYNC to VIN through R<sub>1</sub>. Pulling the SYNC pin LOW, forces the module into PFM mode, which enables pulse-skipping at light load to minimize the switching loss by reducing the switching frequency. Refer to ISL8205M datasheet for more detailed information. For ISL8205MEVAL1Z, PFM mode can be enabled by removing R<sub>1</sub> and shorting SYNC to SGND by putting a 0 $\Omega$  resistor on R<sub>2</sub>.

#### Soft Start-Up

The soft start-up reduces the inrush current during the start-up. For ISL8205MEVAL1Z, the soft start-up time is set to 1ms by default through C<sub>6</sub>. However, start-up time can be adjusted by tuning the C<sub>6</sub> value. Equation 3 can be used to determine the C<sub>6</sub> value for the target soft-start time t<sub>SS</sub>.

 $C_{6}[\mu F] = 3.1 \times t_{SS}[S]$  (EQ. 3)

### **Evaluation Board Information**

The ISL8205MEVAL1Z evaluation board is a 2x2in<sup>2</sup> four-layer FR-4 board with 2oz. copper on all the layers. The board can be used as a single 5A reference design. Refer to Figures 11 through 14 for board layout information. The board is designed with mechanical switches for ENABLE, power-good LED indicators, several connectors, test points and jumpers, which make testing the board easy.

### Thermal Considerations and Current Derating

Board layout is very critical in order to make the module operate safely and deliver maximum allowable power. In order for the board to operate properly in the high ambient temperature environments and carry full load currents, the board layout needs to be carefully designed to maximize thermal performance. To achieve this, select enough trace width, copper weight and proper connectors.

The ISL8205MEVAL1Z evaluation board is capable of operating at 5A full load current at room temperature with plenty of safety margin for junction temperature. However, if the board is to operate at elevated ambient temperatures, then the available output current may need to be derated. Refer to the derated current curves in the <u>ISL8205M</u> datasheet to determine the maximum output current the evaluation board can supply.



### ISL8205MEVAL1Z Schematic



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FIGURE 10. SCHEMATIC

ISL8205MEVAL1Z

### **Bill of Materials**

REFERENCE DESIGNATOR	QTY	MANUFACTURER	PART NUMBER	DESCRIPTION
C16	1	MURATA	GRM21BR71A475KA73L	CAP, SMD, 0805, 4.7µF, 10V, 10%, X7R, ROHS
C12	1	ток	CGA2B2C0G1H331J050BA	CAP, SMD, 0402, 330pF, 50V, 5%, NP0, ROHS
C6	1	PANASONIC	ECU-E1E332KBQ	CAP, SMD, 0402, 3300pF, 25V, 10%, X7R, ROHS
C13	1	YAGEO	CC0402JRNP09BN391	CAP, SMD, 0402, 390pF, 50V, 5%, NP0, ROHS
C14, C15	2	SAMSUNG	CL05C821JB5NNNC	CAP, SMD, 0402, 820pF, 50V, 5%, NP0, ROHS
C4, C5	0			CAP, SMD, 0402, DNP-PLACE HOLDER, ROHS
C2, C3, C7, C8	4	TAIYO YUDEN	LMK316AB7226KL-TR	CAP, SMD, 1206, 22µF, 10V, 10%, X7R, ROHS
C1, C9	0			CAP, SMD, 1206, DNP-PLACE HOLDER, ROHS
TP1-TP8	8	KEYSTONE	5002	CONN-MINI TEST POINT, VERTICAL, WHITE, ROHS
BAN1-BAN4	4	KEYSTONE	575-4	CONN-JACK, MINI BANANA, 0.175 PLUG, NICKEL/BRASS, ROHS
J1	1	BERG/FCI	68000-236HLF	CONN-HEADER, 1x8, BRKAWY 1x36, 2.54mm, ROHS
J1-Pins 5-6	1	SULLINS	SPC02SYAN	CONN-JUMPER, SHORTING, 2PIN, BLACK, GOLD, ROHS
LED1	1	LITEON/VISHAY	LTST-C190KGKT	LED, SMD, 0603, GREEN CLEAR, 2V, 20mA, 571nm, 35mcd, ROHS
U1	1	INTERSIL	ISL8205MIRZ	IC-5A PWR MODULE, ANALOG DC/DC, 22P, QFN 4.5x7.5, ROHS
Q1	1	DIODES, INC.	2N7002-7-F	TRANSISTOR, N-CHANNEL, 3LD, SOT-23, 60V, 115mA, ROHS
R12	1	TE CONNECTIVITY	3-1879216-2	RES, SMD, 0402, 150k, 1/16W, 0.1%, TF, ROHS
R9	1	TE CONNECTIVITY	6-1879215-6	RES, SMD, 0402, 22.1k, 1/16W, 0.1%, TF, ROHS
R11	1	TE CONNECTIVITY	9-1879208-7	RES, SMD, 0402, 100k, 1/16W, 0.1%, TF, ROHS
R4	0			RES, SMD, 0603, 0.1%, MF, DNP-PLACE HOLDEF
R5, R15	2	VENKEL	CR0402-16W-00T	RES, SMD, 0402, 0Ω, 1/16W, 5%, TF, ROHS
R1	1	ROHM	MCR01MZPF2003	RES, SMD, 0402, 200k, 1/16W, 1%, TF, ROHS
R2, R6, R16	0			RES, SMD, 0402, DNP, DNP, DNP, TF, ROHS
R13	1	VENKEL	CR0603-10W-1003FT	RES, SMD, 0603, 100k, 1/10W, 1%, TF, ROHS
R14	1	КОА	RK73H1JTTD2001F	RES, SMD, 0603, 2k, 1/10W, 1%, TF, ROHS
R3	1	VENKEL	CR0603-10W-2003FT	RES, SMD, 0603, 200k, 1/10W, 1%, TF, ROHS
R7	1	STACKPOLE	RNCF0402DTE124K	RES, SMD, 0402, 124k, 1/16W, 0.5%, TF, ROHS
R10	1	YAGEO	RT0402BRD0731K6L	RES, SMD, 0402, 31.6k, 1/16W, 0.1%, TF, ROHS
SW1	1	ITT INDUSTRIES/C&K DIVISION	GT11MSCBE	SWITCH-TOGGLE, SMD, 6PIN, SPDT, 2POS, ON-NONE-ON, ROHS
C10	0			CAP, TANT, SMD, 2917, 10V, DNP-PLACE HOLDE
C11	0			CAP, TANT POLY, SMD, 2917, 10V, DNP-PLACE HOLDER

### **Board Layout**



FIGURE 11. TOP LAYER (TOP VIEW)



FIGURE 12. INNER LAYER 1 (TOP VIEW)



FIGURE 13. INNER LAYER 2 (TOP VIEW)



FIGURE 14. BOTTOM LAYER (BOTTOM VIEW)

### ISL8205MEVAL1Z Performance Data The following data was acquired using a ISL8205MEVAL1Z evaluation

board at +25  $^{\circ}\text{C}$  ambient and free air 0LFM.



FIGURE 15. EFFICIENCY  $T_A = +25 \degree C$ ,  $V_{IN} = 3.3V$  PFM MODE







FIGURE 17. EFFICIENCY T<sub>A</sub> = +25 °C, V<sub>IN</sub> = 3.3V PWM MODE







FIGURE 18. EFFICIENCY T<sub>A</sub> = +25 °C, V<sub>IN</sub> = 5V PWM MODE





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### ISL8205MEVAL1Z Performance Data The following data was acquired using a ISL8205MEVAL1Z evaluation

board at +25°C ambient and free air OLFM. (Continued)



FIGURE 21. THERMAL IMAGE AT V<sub>IN</sub> = 5V, V<sub>OUT</sub> = 1.2V, I<sub>OUT</sub> = 5A,  $f_{SW}$  = 1.6MHz,  $T_A$  = +25 °C, FREE AIR 0 LFM



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(Rev.4.0-1 November 2017)



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